F	
C]
1000	?
	,

AF	bon
~ ~/	•

AMENDMENT TRANSMITTAL LETTER

Docket No. M4065.0223/P223

Application No.	Filing Date	Examiner	Art Un
09/517,314	March 2, 2000	Donghee Kang	2811

Applicant(s): Chih-Chen Cho

Invention: BACKEND METALLIZATION METHOD AND DEVICE OBTAINED THEREFROM

TO THE COMMISSIONER FOR PATENTS

Transmitted herewith is an amendment in the above-identified application.

The fee has been calculated and is transmitted as shown below.

		CLAIM	S AS AMENI	DED	
	Claims Remaining After Amendment	Highest Number Previously Paid	Number Extra Claims Present	Rate	
Total Claims	23	- 31 =		x	0.00
Independent Claims	3	- 4 =		х	0.00
Multiple Depen	dent Claims (ch	eck if applicabl	e)		
Other fee (pleas	se specify):				
TOTAL ADDIT	TIONAL FEE FO	OR THIS AME	NDMENT:		0.00
x Large Entity	/			Small Enti	ity
x No addition	al fee is require	d for this amer	ndment.		
	rge Deposit Acc			n the amount of \$	·
A check in t	the amount of \$		to cover	the filing fee is e	nclosed.
Payment by	credit card. Fo	m PTO-2038	is attached.		
	issioner is hereb d below. A dup				ccount No04-1073
x Credit a	any overpaymer	ıt.			
× Ctrarge	any additional fili	ng or applicatio	n processing t	fees required unde	er 37 CFR 1.16 and 1.17.
Stephen A. So Attorney Reg.		1/		Dated:	July 30, 2002
· -	HAPIRO MORII	N & OSHINSK	YIIP		
2101 L Street I	NW		r tolul		
Washington, D (202) 828-2232	OC 20037-1526 2				TECHNO



DEST AVAILABLE COPY (PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:

Chih-Chen Cho

Application No.: 09/517,214

Filed: March 2, 2000

For: BACKEND METALLIZATION METHOD AND DEVICE OBTAINED THEREFROM

Group Art Unit: 2811

Examiner: Donghee Kang

Am St ple Sinceredor S/2/02 Ester 11

AMENDMENT UNDER 37 CFR §1.116

ATTN: Box AF

Commissioner for Patents Washington, DC 20231

Dear Sir:

This paper is in response to the Office Action dated April 30, 2002, finally rejecting claims 1, 3-18, 20-32, and 39, please amend the above-captioned U.S. Patent application as follows:

In the Claims:

Please cancel claims 12, 18, 20-24, and 26 without prejudice or disclaimer to the subject matter recited therein.

Please replace claims 11, 15, 16, 25, 27, 28, 30, 31, and 32.

11. (Twice Amended) A semiconductor device comprising:

at least one memory cell comprising:

an active region in a substrate;

RECEIVED

AUG-2 2002